

Bidirectional DIAC Trigger Diode

Features

- Low breakover current: 15µA Max.
- Excellent symmetry
- Very low leakage current
- Trigger diode with a fixed voltage reference
- High temperature soldering guaranteed:
250°C/10s/9.5mm lead length at 5 lbs tension
- RoHS Compliance



DO-35



Mechanical Data

Case:	Glass Case DO-35
Terminals:	Plated axial leads, solderable per MIL-STD-750, method 2026
Weight:	Approx. 0.13 gram

Maximum Ratings and Electrical Characteristics ($T_A=25^\circ\text{C}$ unless noted otherwise)

Symbol	Description	Value			Unit	Conditions
		Min.	Typ.	Max.		
V_{BO}	Breakover Voltage*	30	32	34	V	$I_{BO}, C=22\text{nF}^{**}$
$ +V_{BO} - -V_{BO} $	Breakover Voltage Symmetry	-2	-	2	V	$I_{BO}, C=22\text{nF}^{**}$
$ \pm\Delta V $	Dynamic Breakover Voltage**	9	-	-	V	V_{BO} and V_F at 10mA
V_O	Output Voltage*	5	-	-	V	See Fig.6 (R=20Ω)
I_{BO}	Breakover Current*	-	-	15	µA	$C=22\text{nF}^{**}$
T_r	Rise Time*	-	-	2	µs	See Fig.5
I_B	Leakage Current*	-	-	10	µA	$V_B=0.5V_{BO}$ Max.
I_P	Peak Current*	0.3	-	-	A	See Fig.6 (Gate)
P_d	Power Dissipation on Printed Circuit	-	-	150	mW	$T_a=50^\circ\text{C}$
I_{TRM}	Repetitive Peak on-state Current	-	-	2	A	$t_p=20\mu\text{s}, f=100\text{Hz}$
R_{thJA}	Typical Thermal Resistance	-	-	400	°C / W	
R_{thJL}		-	-	150	°C / W	

Bidirectional DIAC Trigger Diode

DB3B

Symbol	Description	Value	Unit	Conditions
T _J	Operating Temperature range	-40 to + 110	°C	
T _{STG}	Storage Temperature Range	-40 to + 125		

*Electrical characteristic applicable in forward and reverse directions.

**Connected in parallel with the devices.

Typical Characteristics Curves

Fig.1-Max. Power Dissipation

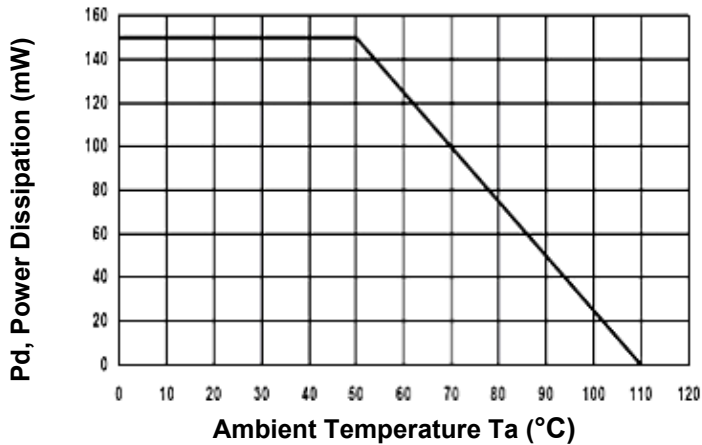


Fig.2- Typical Relative Variation of VBO

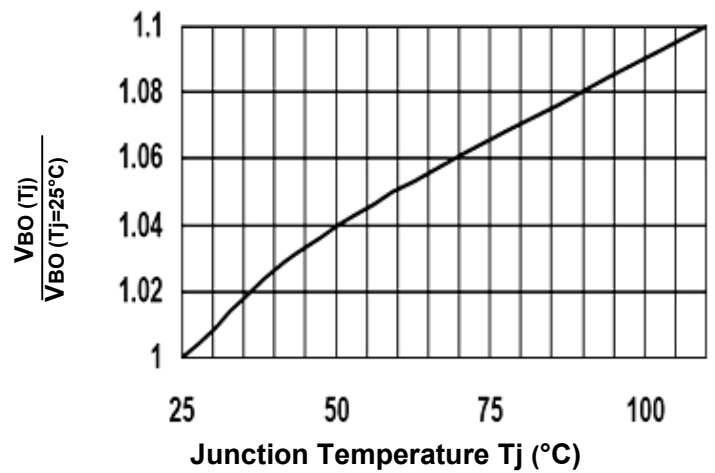


Fig.3- Peak Pulse Current

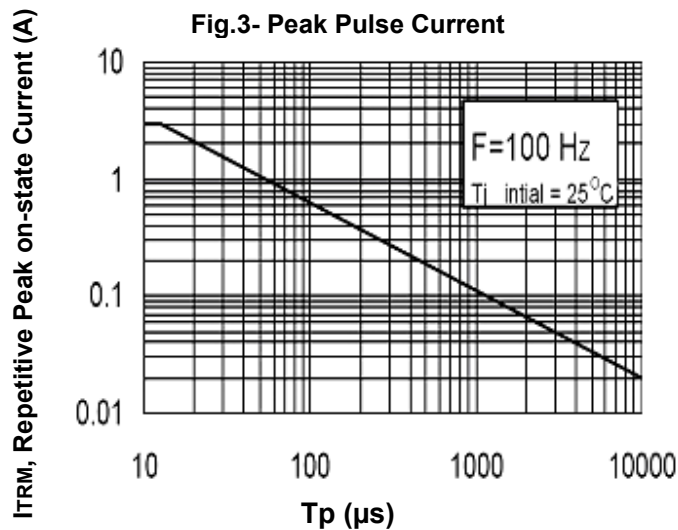


Fig.4-Voltage – Current characteristic Curve

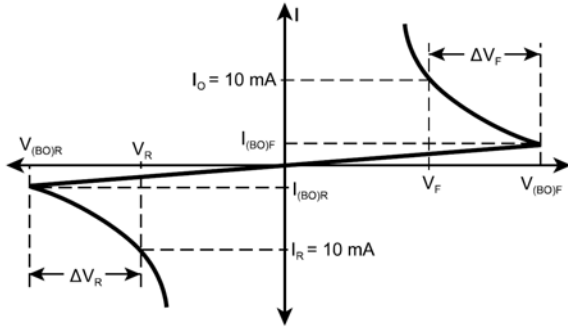


Fig.5- Rise Time Measurement

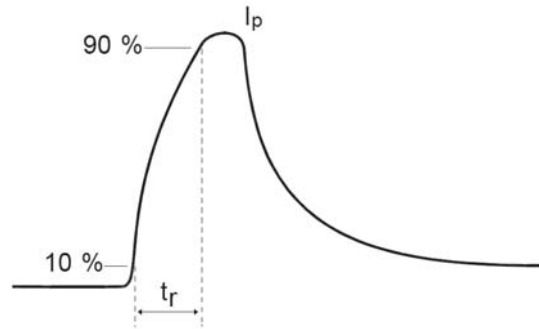
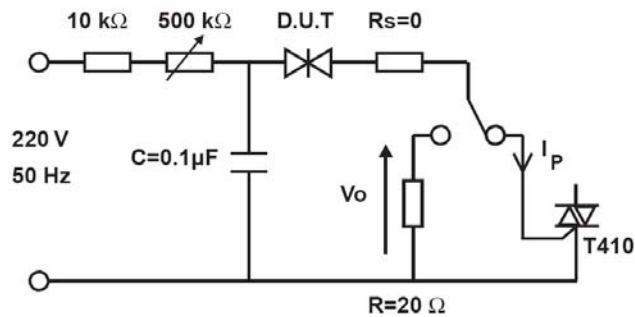


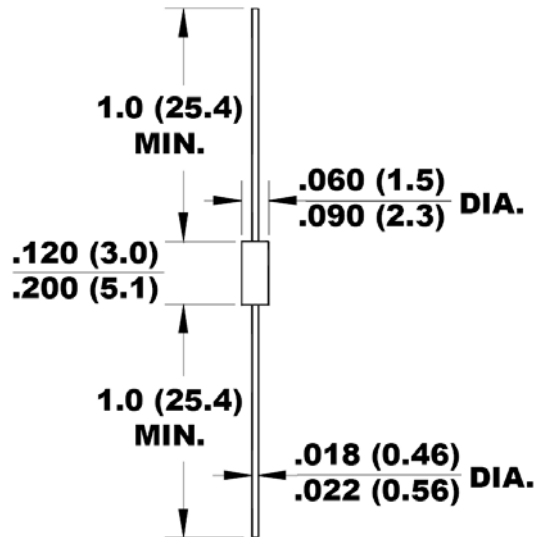
Fig.6-Test Circuit for Output Voltage



Bidirectional DIAC Trigger Diode

DB3B

Dimensions in inches (mm)



DO-35

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